

Doing More with Less: Opportunities for Increased Energy Efficiency

Moderator: Dr. Tim Heidel, ARPA-E

Dr. James Klausner, ARPA-E

Dr. Amul Tevar, ARPA-E

Dr. Bradley Zamft, ARPA-E

Overview of this session



Tim Heidel, ARPA-E Program Director
ADEPT & SWITCHES Programs



James Klausner, ARPA-E Program Director
*Metals Production Consumes Significant Energy:
ARPA-E Seeks Energy Efficiency*

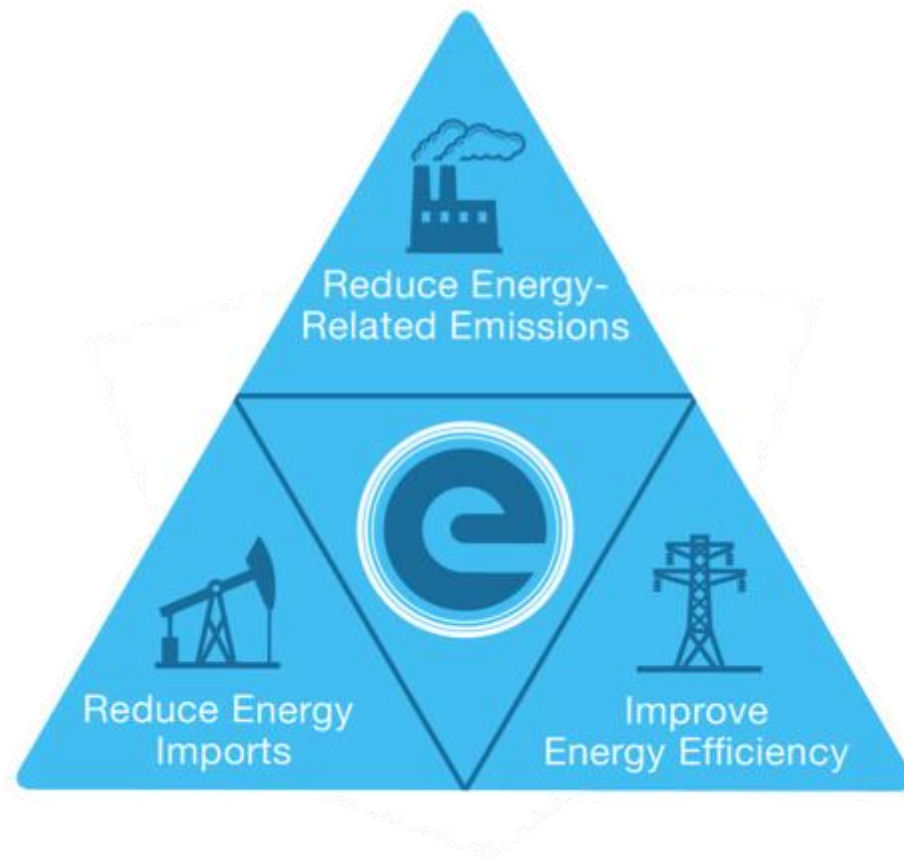


Bradley Zamft, ARPA-E Fellow
*Microorganisms for Metals: Opportunities for
Biology in the Mining Industry*

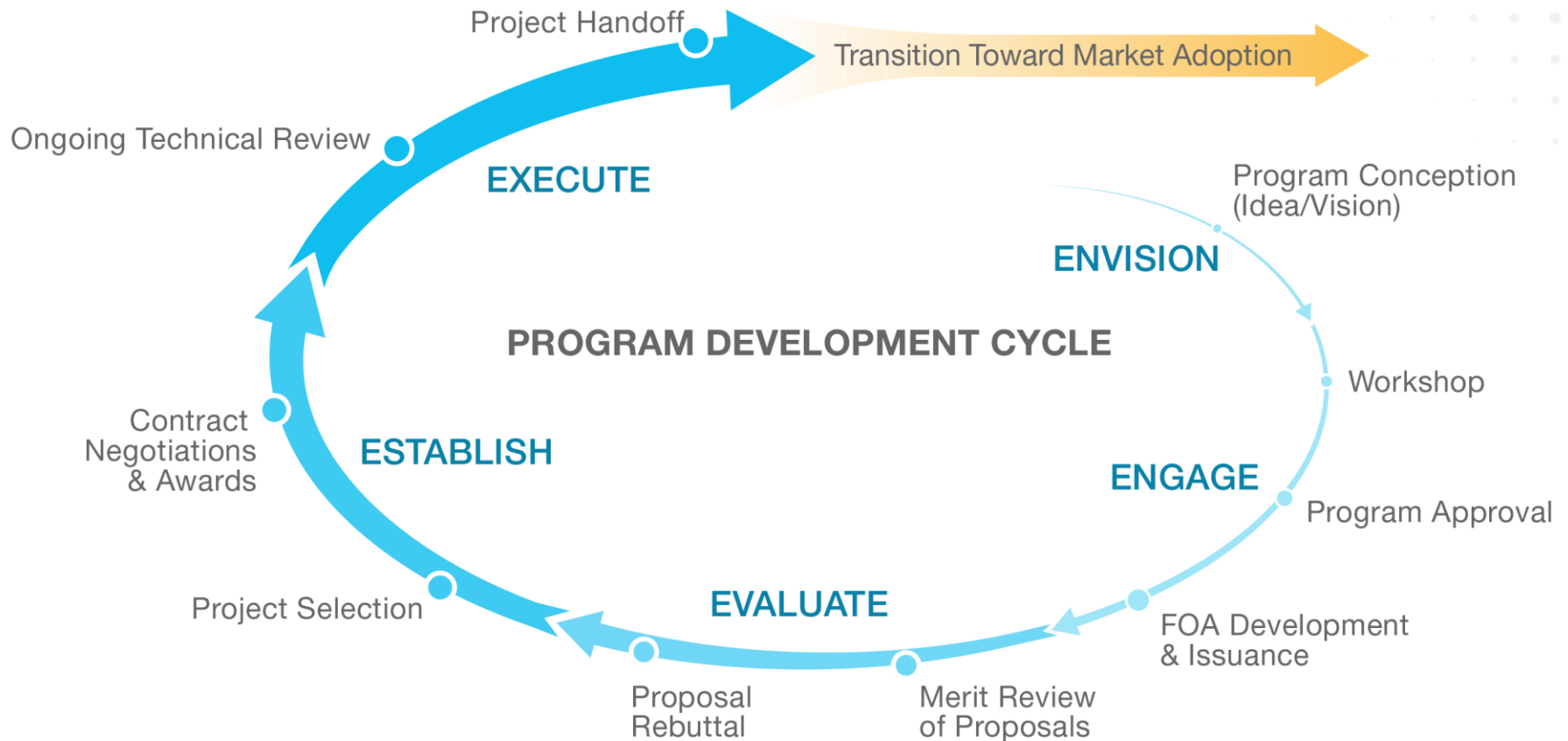


Amul Tevar, ARPA-E Fellow
The Far Future of the Energy & Water Nexus

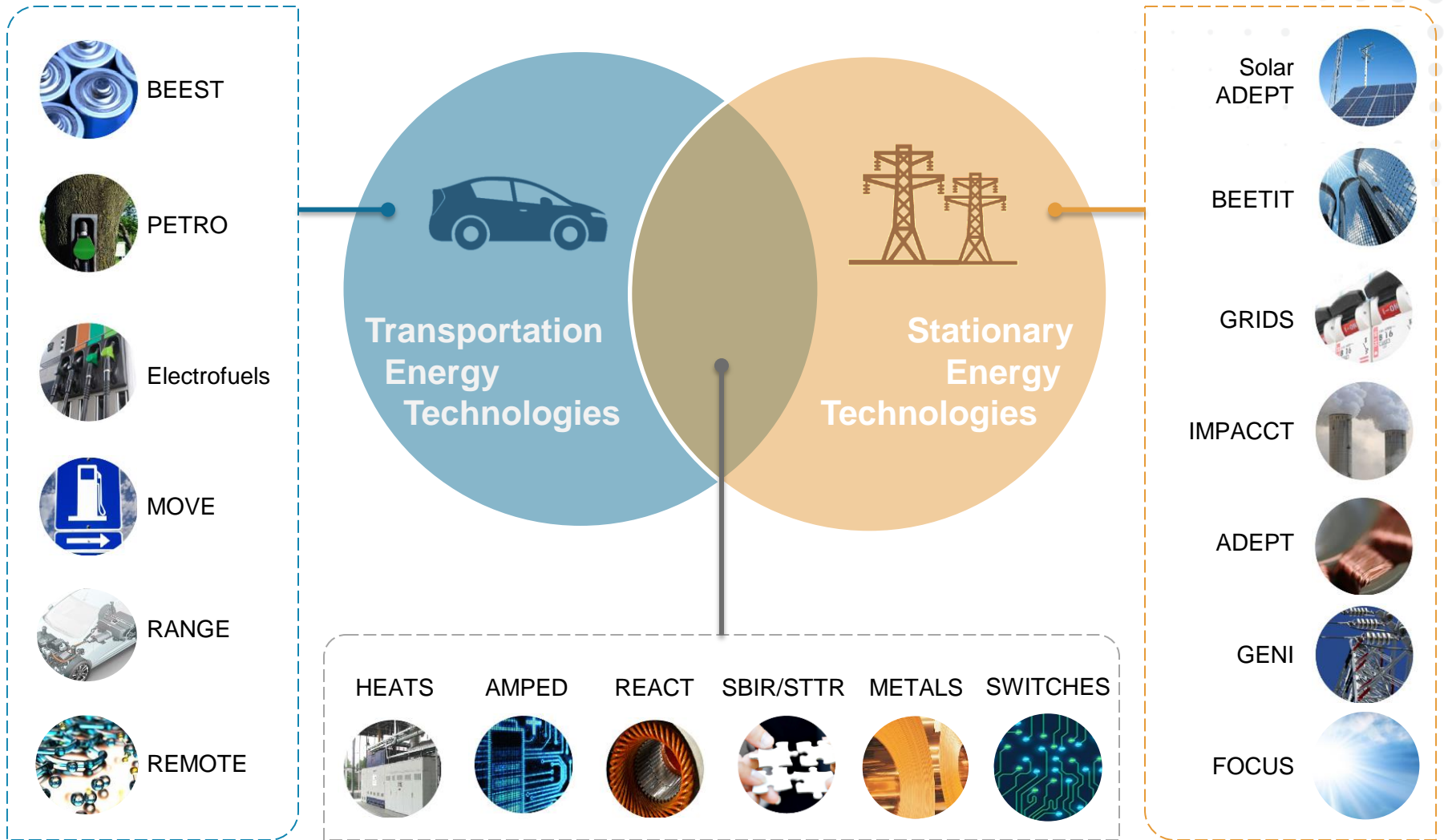
ARPA-E Mission



Technology Acceleration Model



Focused Programs



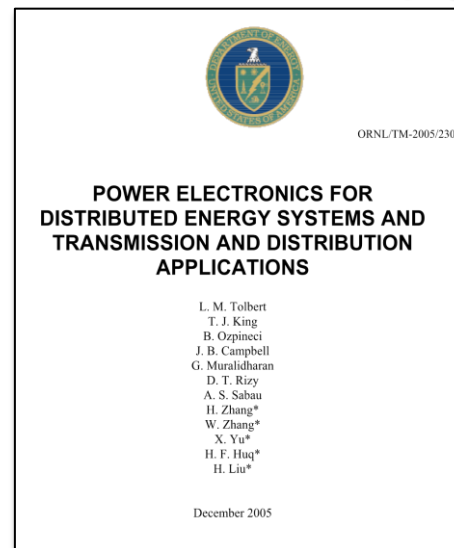
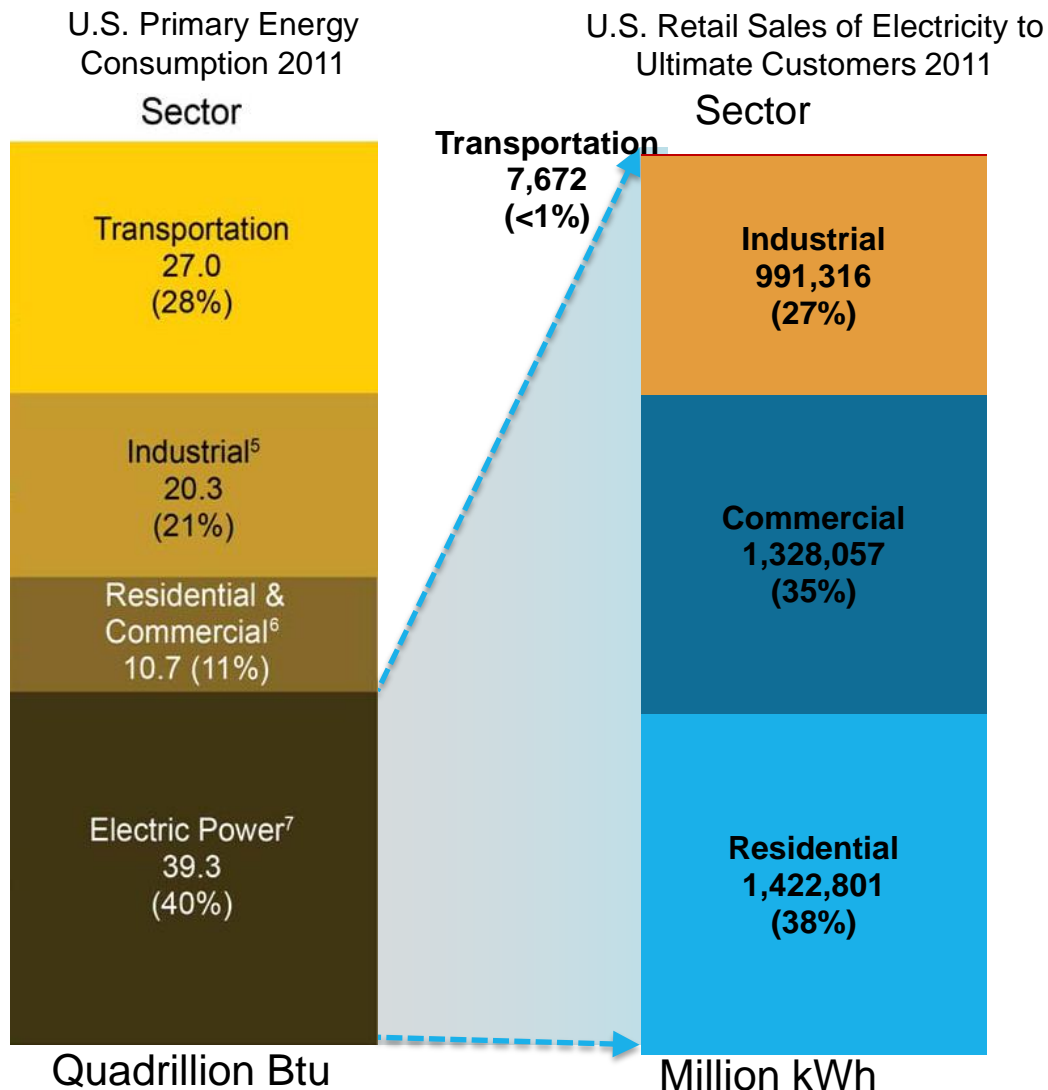
ARPA-E Investments in Power Electronics

ADEPT & SWITCHES Programs

Dr. Tim Heidel, Program Director



Electricity is ~40% of U.S. Energy Consumption



- In 2005, **30%** of electricity in the U.S. flows through power converters.
- By 2030, **80%** of electricity could flow through power converters.

ADEPT

EFFICIENT POWER CONVERSION



Goals




- Improve the energy efficiency of electronic devices and power systems
- Enable high efficiency, high power density power electronics
- Contribute to the development of a smart grid

Program Director	Dr. Tim Heidel (Dr. Rajeev Ram)
Kickoff Year	2010
Projects	13
Total Investment	\$37.7 Million

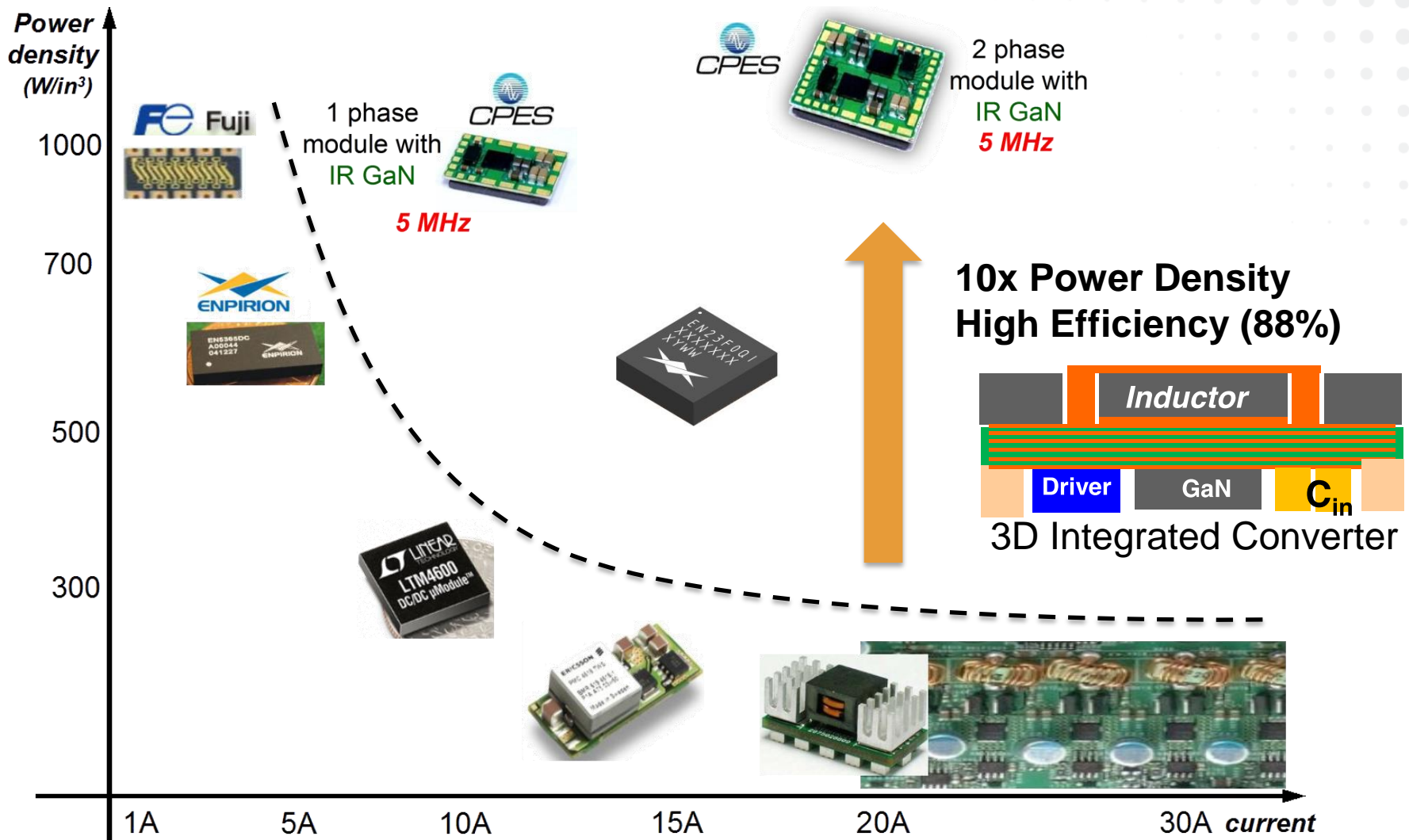
Highlights

- Advanced charge storage devices
- Magnetic materials
- Advanced solid-state switch technologies
- Advanced circuit topologies and converter architectures

ADEPT Program Technical Targets

Category	Voltage & Power	Efficiency	Switching Frequency	Power Density	Applications
Fully Integrated, Chip-scale power converters	>100V 10-50W	>93%	>5 MHz	>300 W/in ³	
Package integrated power converters	>600V 3-10kW	>95%	>1 MHz	>150 W/in ³	
Lightweight, solid-state, medium voltage energy conversion	13kV 1MW	>98%	>50 kHz	N/A	

High Power Density Point of Load Converter



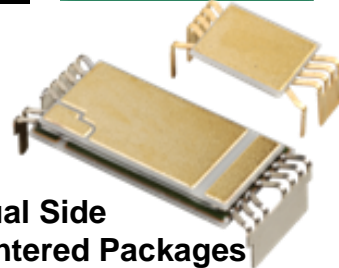
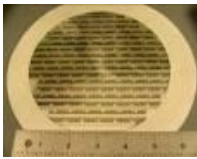
Automotive Applications

Vehicle Inverter (GaN)

DELPHI



IGR International Rectifier



6" GaN/Si Wafer

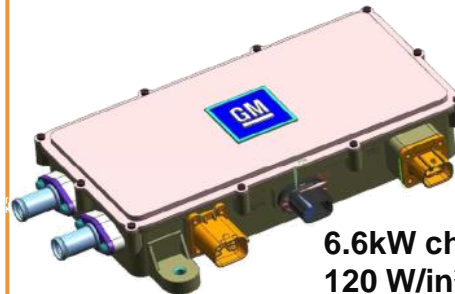
Dual Side Sintered Packages



GaN Inverter

600V GaN-on-Si Dual Side Cooled Transistors, 50% Lower Cost, 50% Lower Losses

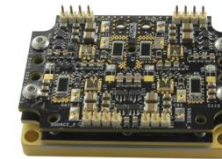
Bi-Directional Vehicle Battery Charger (GaN)



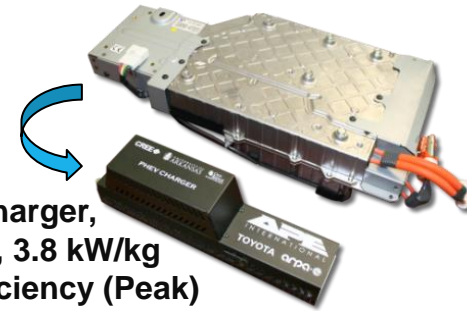
6.6kW charger, 120 W/in³

2x faster charging, 2x more efficient, 10x more compact

Bi-Directional Vehicle Battery Charger (SiC)



Multi-chip Power Module (MCPM) (1 MHz Operation)

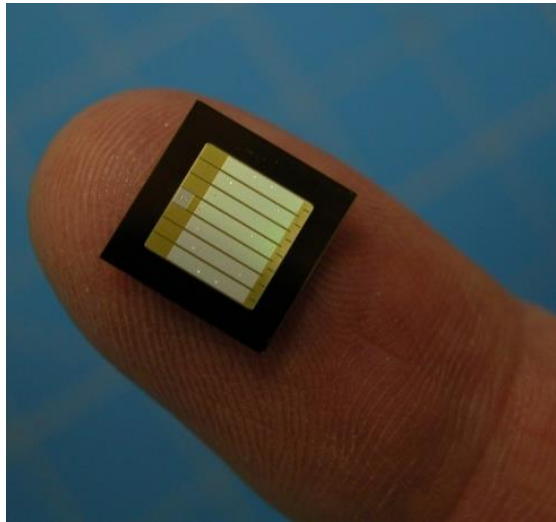


6.1kW charger, 83 W/in³, 3.8 kW/kg, 95% Efficiency (Peak)

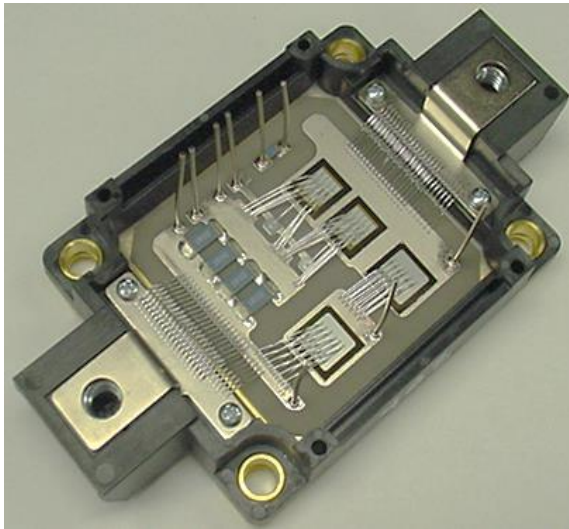
10x Increase in Power Density and Increased Efficiency

15kV+ SiC IGBTs, Solid State Transformers

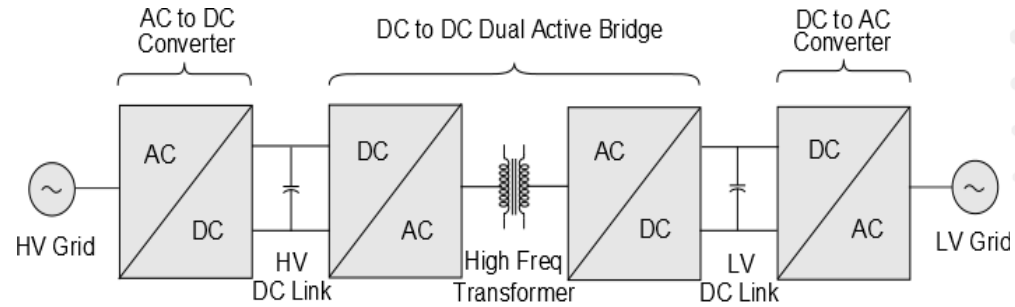
19 kV/20 A
SiC n-IGBT



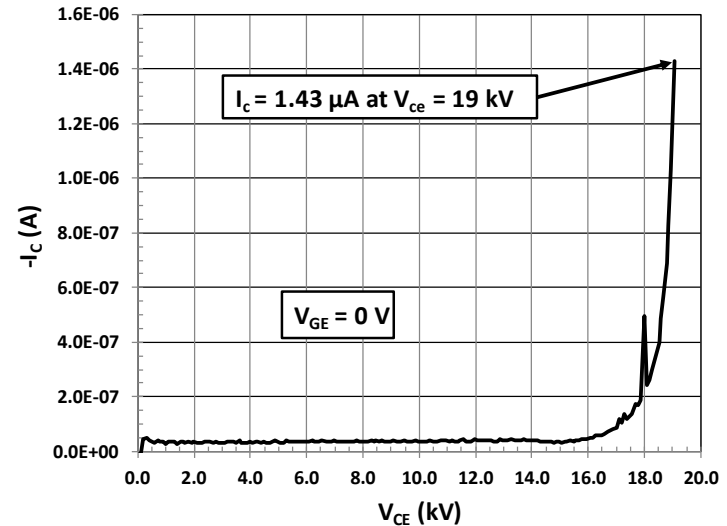
15kV/40A
SiC IGBT
Copack



Transformerless Intelligent Power Substation (TIPS)

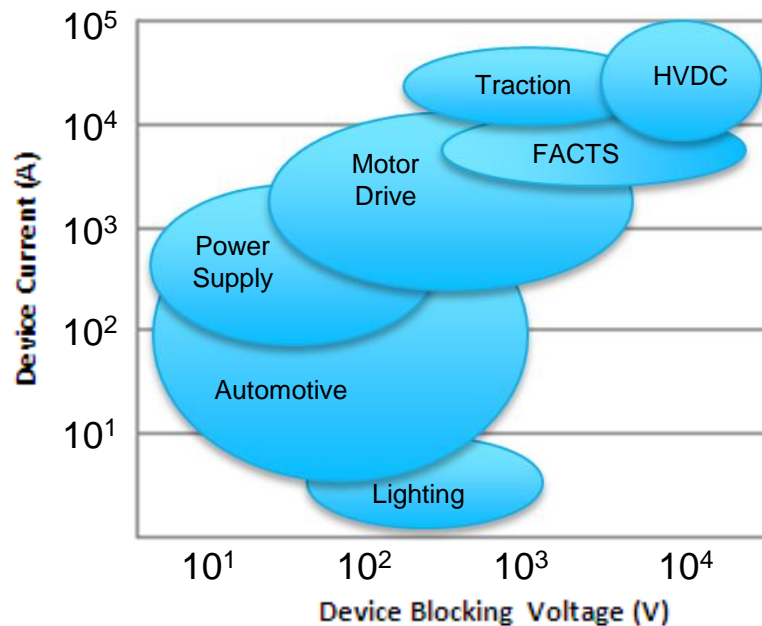


19 kV/20A SiC n-IGBT Reverse Blocking



SWITCHES Program Builds on ADEPT Success

Application Areas and Limits



• Key Device Parameters:

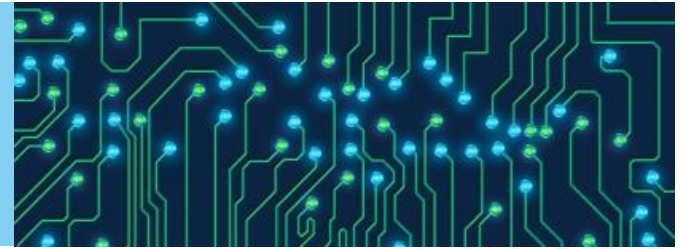
- Breakdown voltage
- Junction temperature
- Switching speed
- Ease of driving
- Current rating
- \$/Amp

**ADEPT
Program
Focus
Areas**

**SWITCHES
Program
Focus
Areas**

SWITCHES

Low Cost, High Current Wide Bandgap Switches



Goals

- High voltage (1200V+), high current (100A) single die power semiconductor devices at functional cost parity with silicon power transistors.
- Reduce the barriers to widespread deployment of low-loss WBG power semiconductor devices in stationary and transportation energy applications.

Program Director	Dr. Tim Heidel
Kickoff Year	2013
Projects	14
Investment	\$27 Million

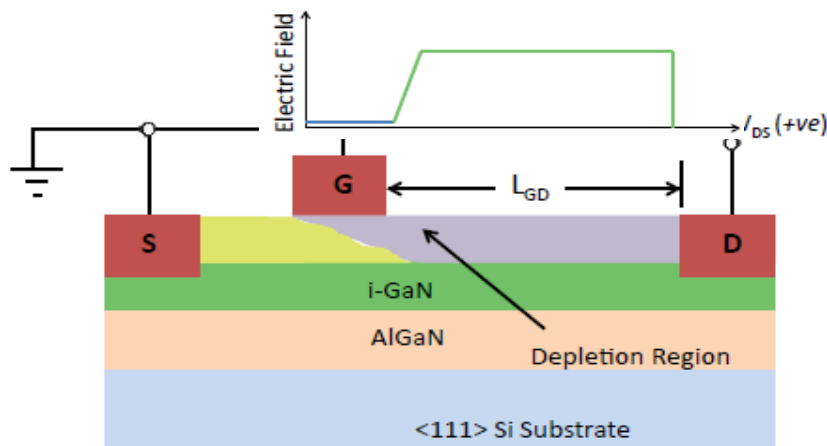
Highlights

- Low Cost (Foundry) SiC Device Fabrication
- Vertical GaN Transistors
- Diamond Semiconductor Devices

Pathways to Low Cost Gallium Nitride Devices

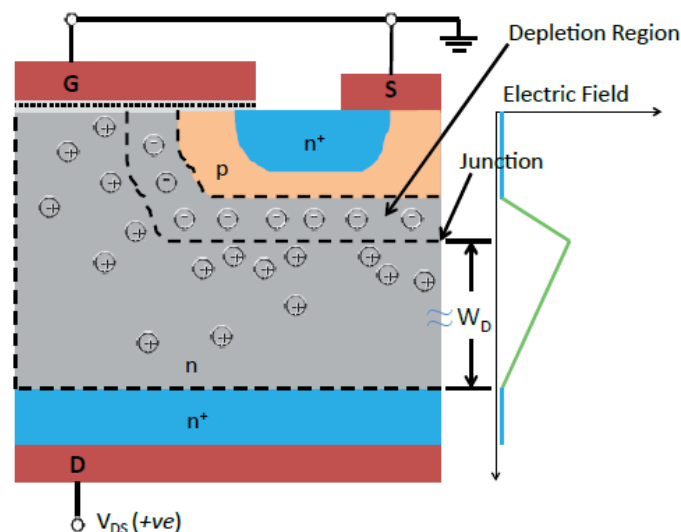
Lateral GaN High Electron Mobility Transistors (HEMTs)

- Lateral conduction: Low current density/die area, die size increases directly with breakdown voltage.
- Heteroepitaxy makes high current devices (>100A) extremely challenging.



Vertical GaN Transistors

- Utilize more of the material for conduction, higher current densities.
- Breakdown voltage handled vertically.
- Challenge: Requires bulk GaN substrates.



Pathways to Low Cost SiC and Diamond Devices

Silicon Carbide

CREE

CMF20120D-Silicon Carbide Power MOSFET
Z-*F_{ET}*™ MOSFET
N-Channel Enhancement Mode

V_{DS} 1200 V
 I_{DMAX} 42 A
 $R_{DS(on)}$ 80m Ω

Features

- High Speed Switching with Low Capacitance
- High Blocking Voltage with Low $R_{DS(on)}$
- Easy to Parallel and Simple to Drive
- Avalanche Ruggedness
- Resistant to Latch-Up
- Halogen Free, RoHS Compliant

Benefits

- Higher System Efficiency
- Reduced Cooling Requirements
- Increased System Switching Frequency

Applications

- Solar Inverters
- High Voltage DC/DC Converters
- Motor Drives
- Switch Mode Power Supplies
- UPS

Package

TO-247-3

RoHS

Part Number: CMF20120D Package: TO-247-3

ROHM

SCH2080KE
N-channel SiC power MOSFET co-packaged with SiC-SBD Datasheet

V_{DS} 1200V
 $R_{DS(on)}$ (Typ.) 80m Ω
 I_D 35A
 P_D 179W

Outline

TO-247-3

Pinout

(1) Gate
(2) Drain
(3) Source
*1 Body Diode
*2 SBD

Features

- Low on-resistance
- Fast switching speed
- Fast reverse recovery
- Low V_{SD}
- Easy to parallel
- Simple to drive
- Pin-free lead plating, RoHS compliant

Application

- Solar inverters
- DC/DC converters
- Induction heating

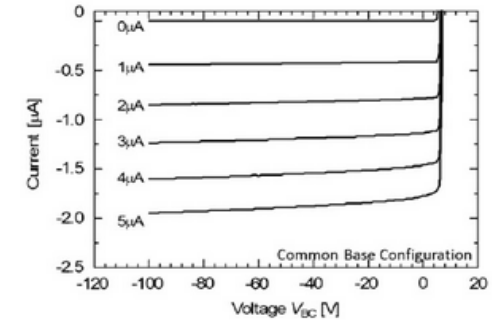
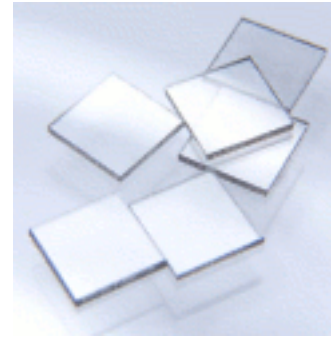
Packaging specifications

	Tube
Packaging	-
Lead size (mm)	-
Lead width (mm)	-
Basic ordering unit (pcs)	30
Taping code	-

Type

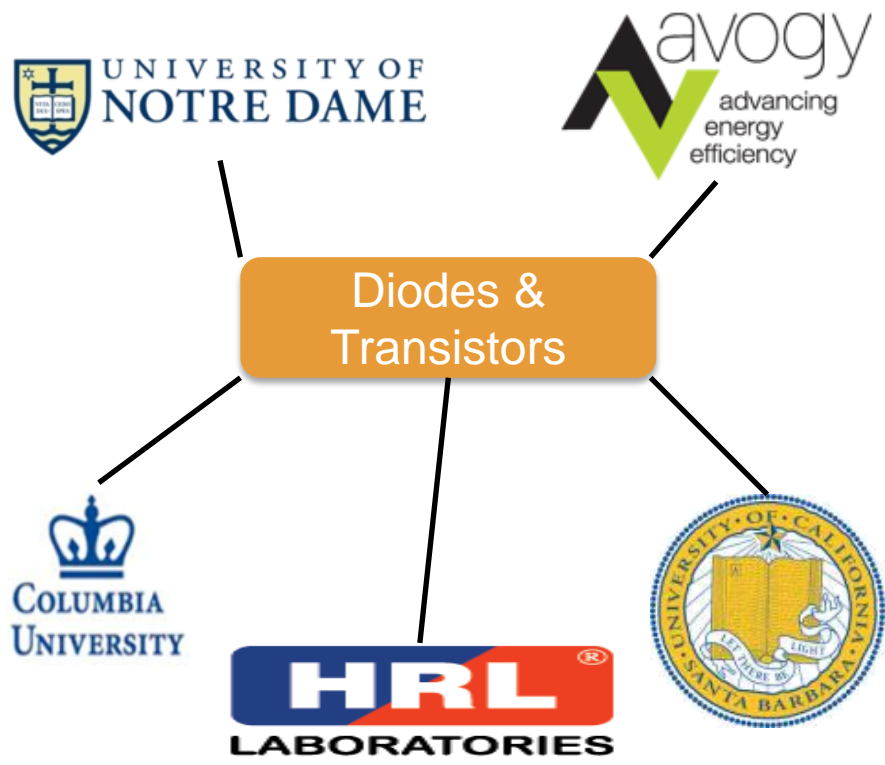
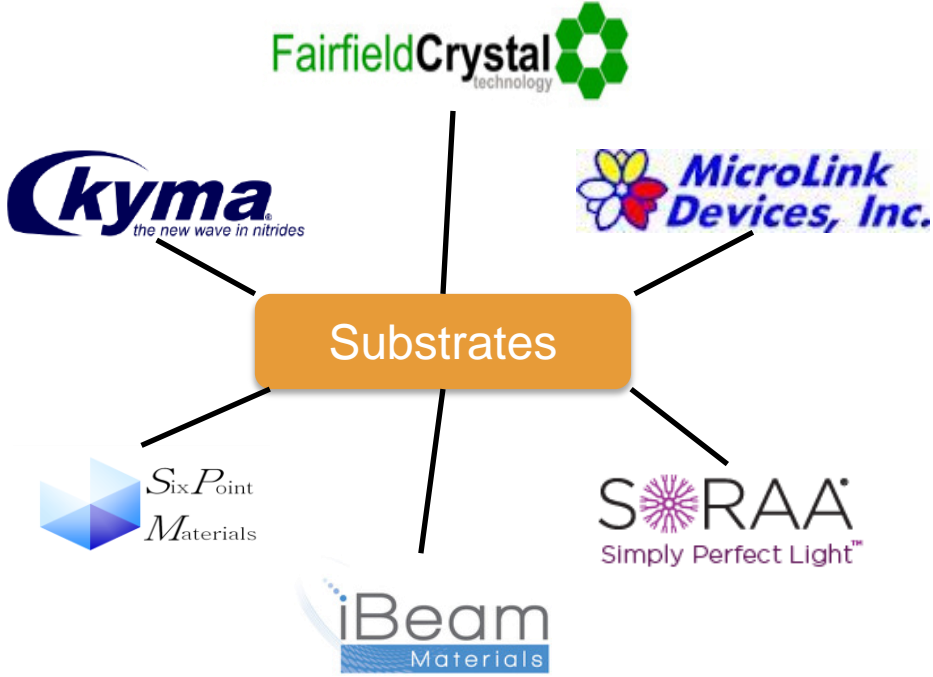
- SiC MOSFETs currently 5-8X more expensive than Si devices (\$/A).
- Challenges:
 - Carrier mobilities substantially below theoretical maximum
 - High temperature processing steps require use of dedicated, custom (low volume) SiC fabrication facilities.

Diamond

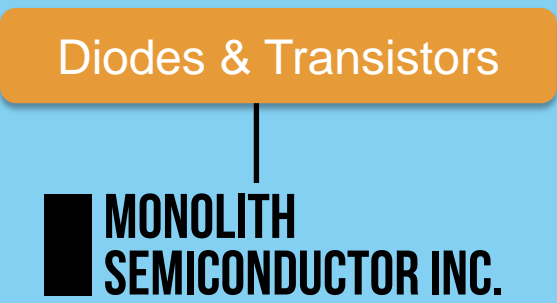


- Diamond material advantages:
 - Very high bandgap (5.45 eV)
 - Superior thermal conductivity
 - High electron mobility
- Why now?
 - Availability of single crystal substrates
 - p-type and n-type epi growth
 - Improved low resistance contacts
 - Demonstration of (low current) BJT

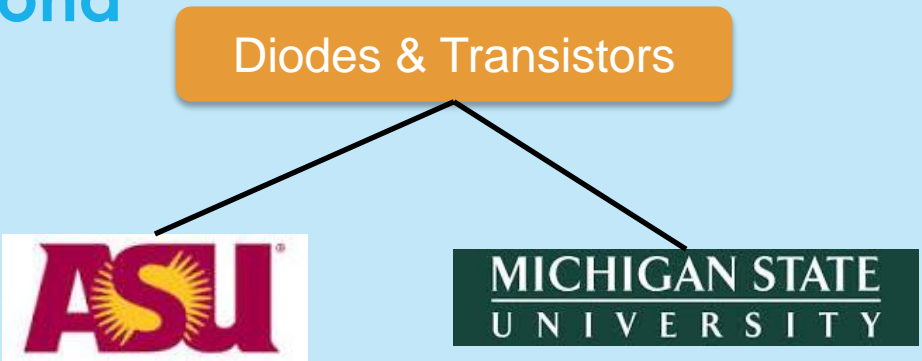
GaN



SiC



Diamond





CHANGING WHAT'S POSSIBLE

Metals Production Consumes Significant Energy: ARPA-E Seeks Energy Efficiency

METALS Program

Dr. James Klausner, Program Director

Program Objectives

- Enable **cost competitive** transformative light metal (Al, Mg, Ti) processing technologies
- Significant **energy reduction** in primary metal production from ore
- Significant **emissions reduction** in primary metal production
- Significantly **increase the supply** of high grade recycled light metal

4 QUADS Energy Savings

Light Metal to be Competitive with Steel

- Light metals (Al, Mg, Ti) enable **advanced alternative energy technologies**

- Drive down:

Energy

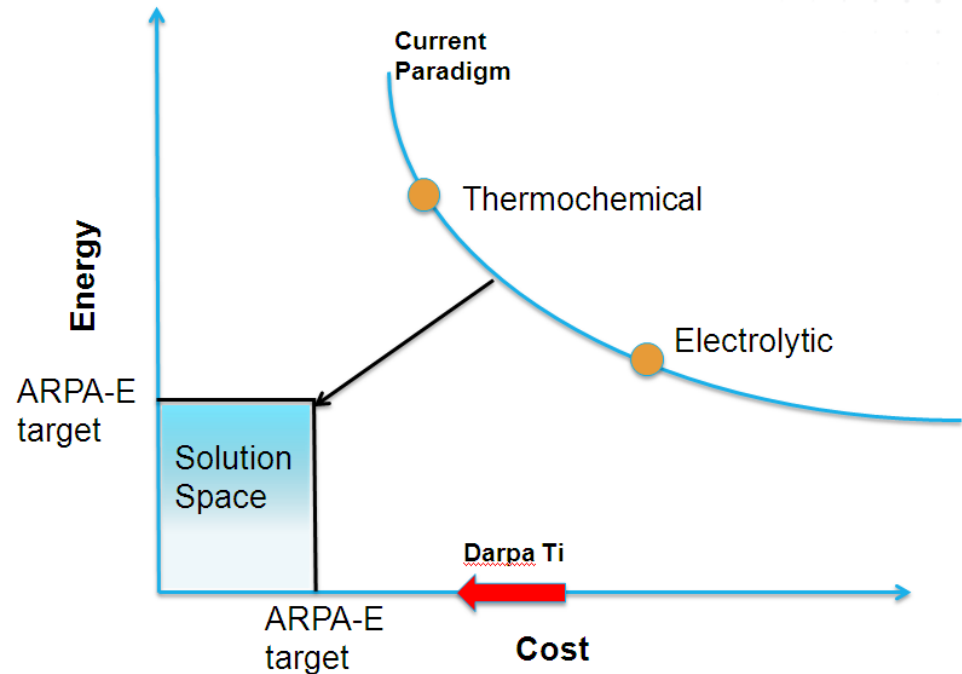
Emissions

Cost



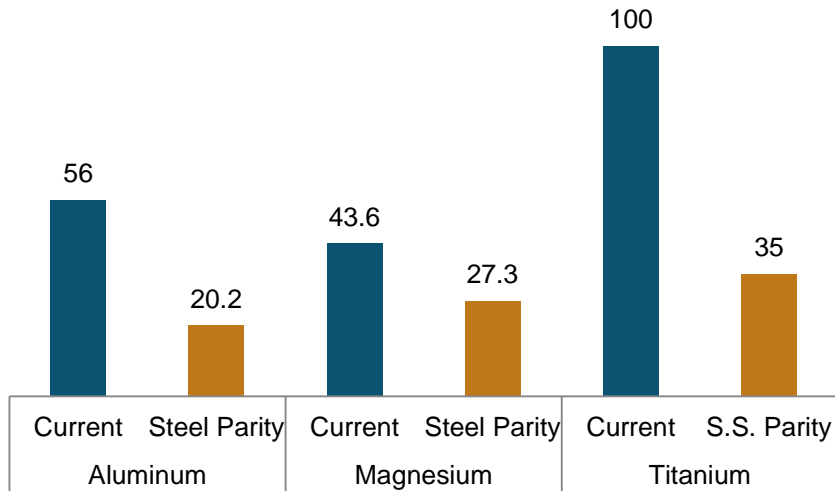
Steel

- Most **competitive light metal production** in the world; significantly reduce imports

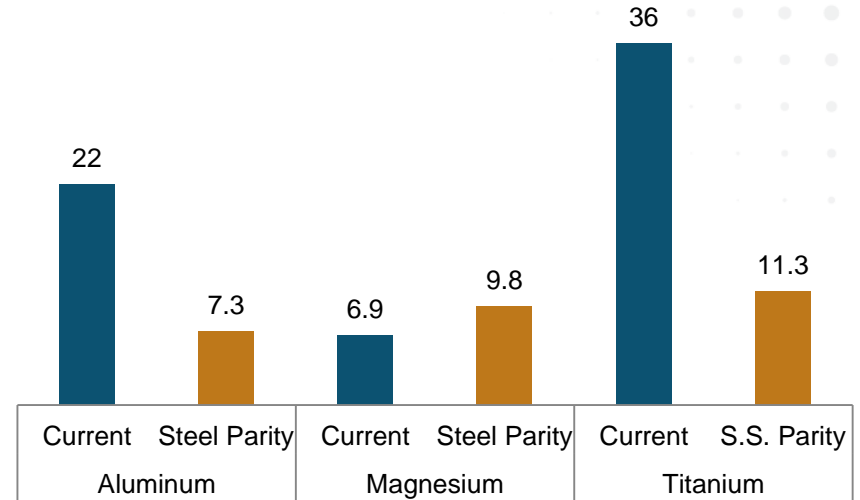


Reach Parity with Steel and Stainless Steel

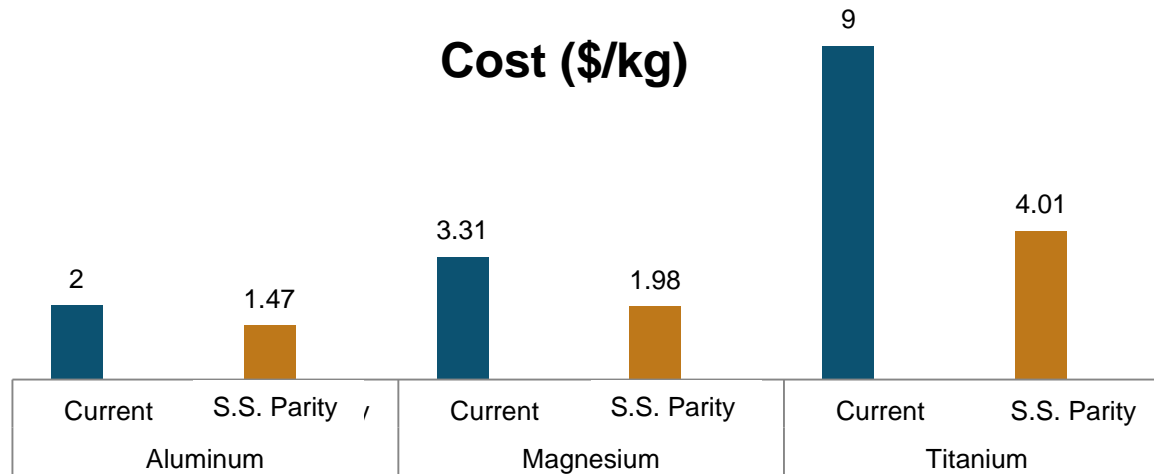
Energy (kWh/kg)



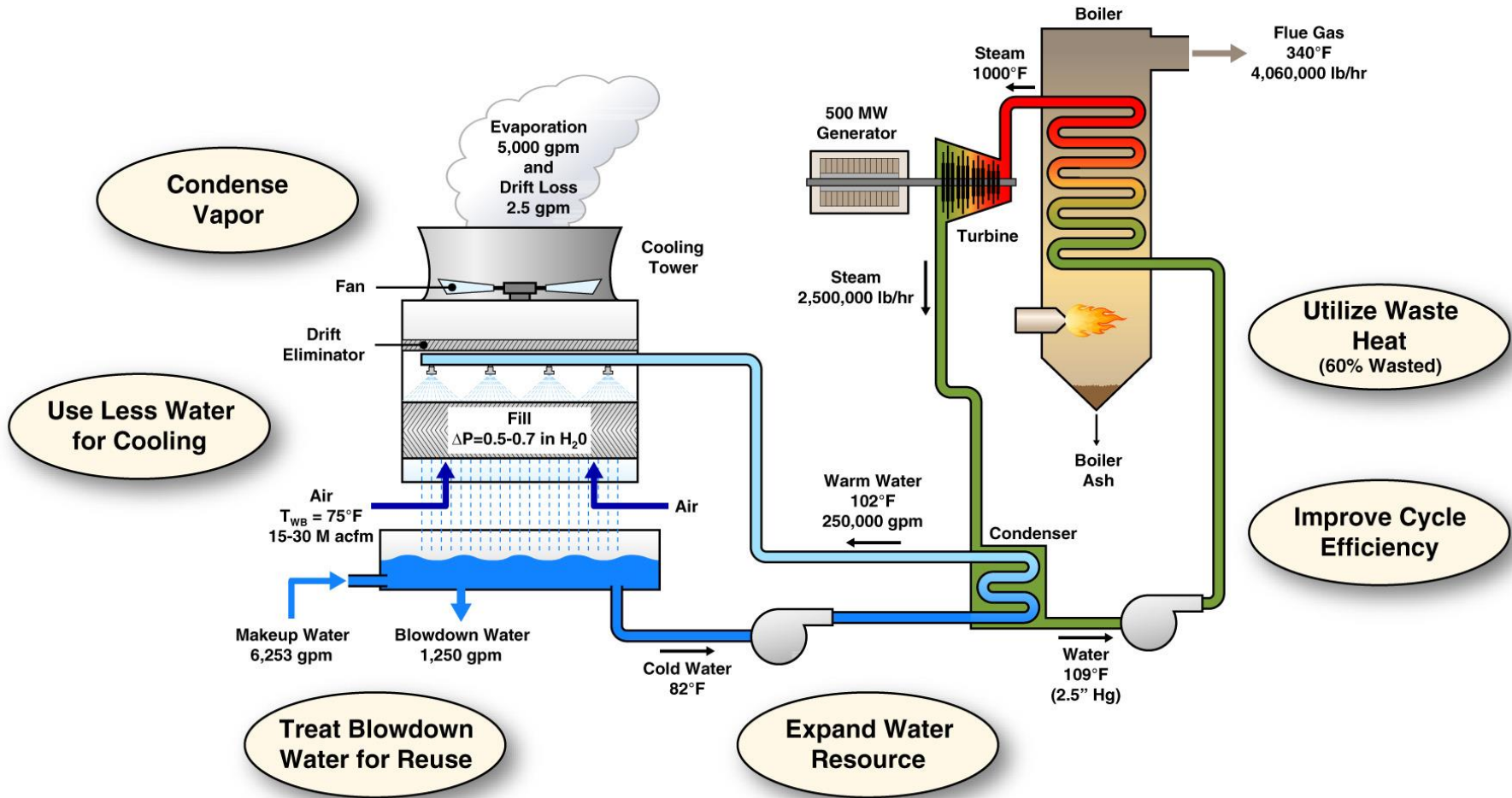
Emissions (kgCO2/kg)



Cost (\$/kg)



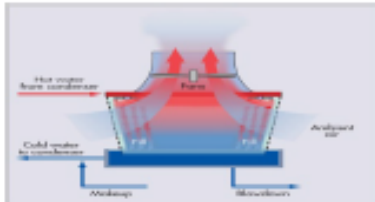
Energy/Water Interest



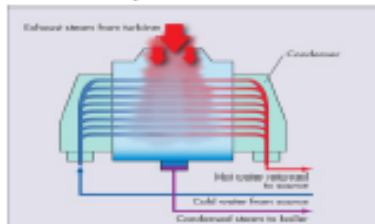
Conventional Power Plant Steam Condenser Technologies

Water Cooling

Cooling Tower¹ (42% in US)²



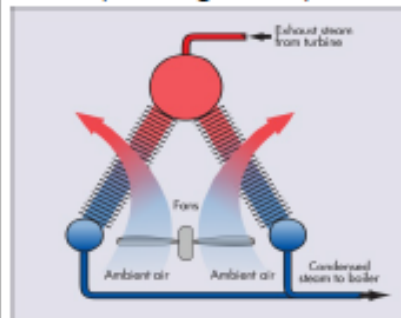
Once Through Cooling¹
(43% in US)²



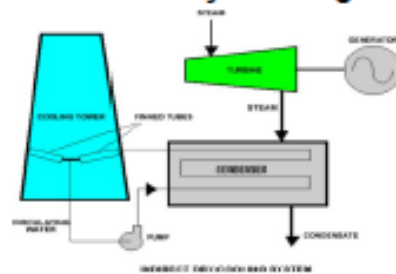
Cooling Pond
(14% in US)²

Dry Cooling

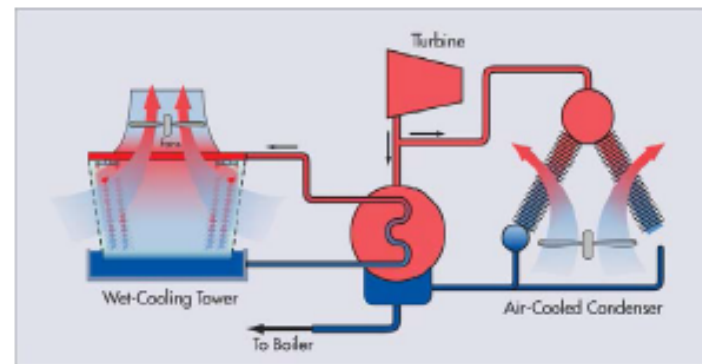
Direct Dry Cooling¹:
Air Cooled Condenser
(1% Usage in US)²



Indirect Dry Cooling³



Hybrid Cooling¹



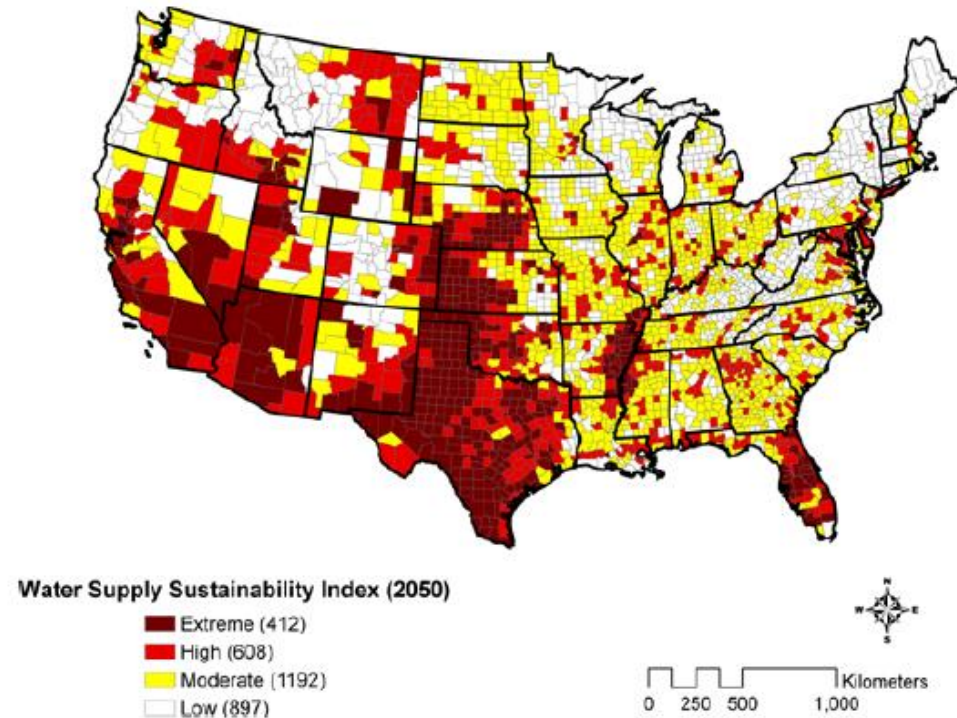
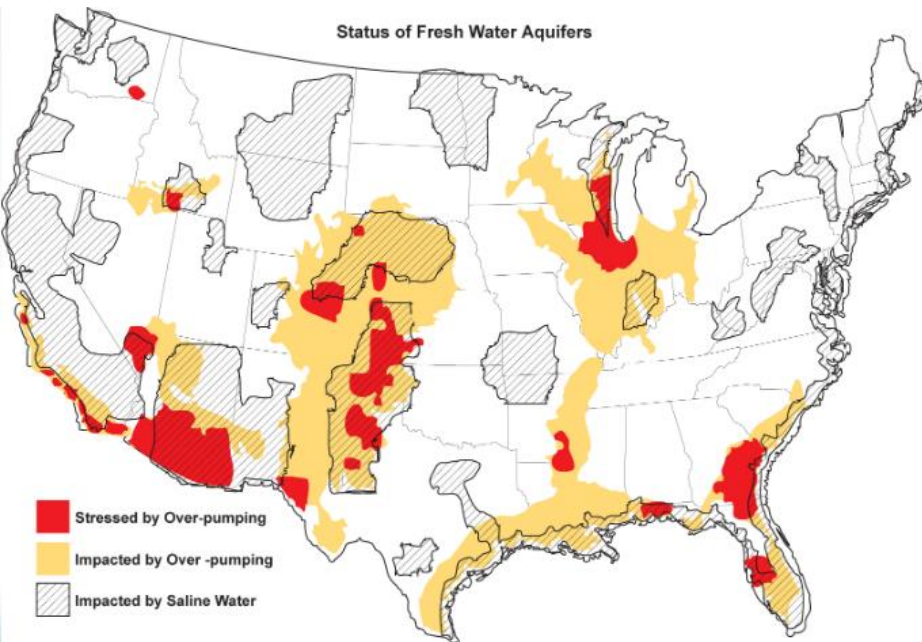
Increasing demand for dry cooling in water scarcity regions.

1. EPRI Report, "Water Use for Electric Power generation", No. 1014026, 2008.
2. Report of Department of Energy, National Energy Technology Laboratory, "Estimating Freshwater Needs to Meet Future Thermoelectric Generation Requirements", DOE/NETL-400/2008/1339, 2008
3. <http://www.globalccsinstitute.com/publications/evaluation-and-analysis-water-usage-power-plants-co2-capture/online/101181>

Energy Conversion Efficiency at Risk due to Growth of Regional Water Supply Problems

Current scenario, more of a **regional problem** (high population centers)

With population growth and climate change, 2050 **water scarcity** is projected to be widespread



ARPA-E Investigating Transformative Power Plant Cooling Technologies

- Advanced high performance **dry cooling technologies**, where heat is dumped to ambient air
- Use excess heat from stack gas to drive absorption cooling to create a **low temperature heat sink**
- Radiant cooling** to sky
- Use **advanced manufacturing** -- i.e., 3D printing to develop complex and efficient heat exchange surfaces with low pressure drop

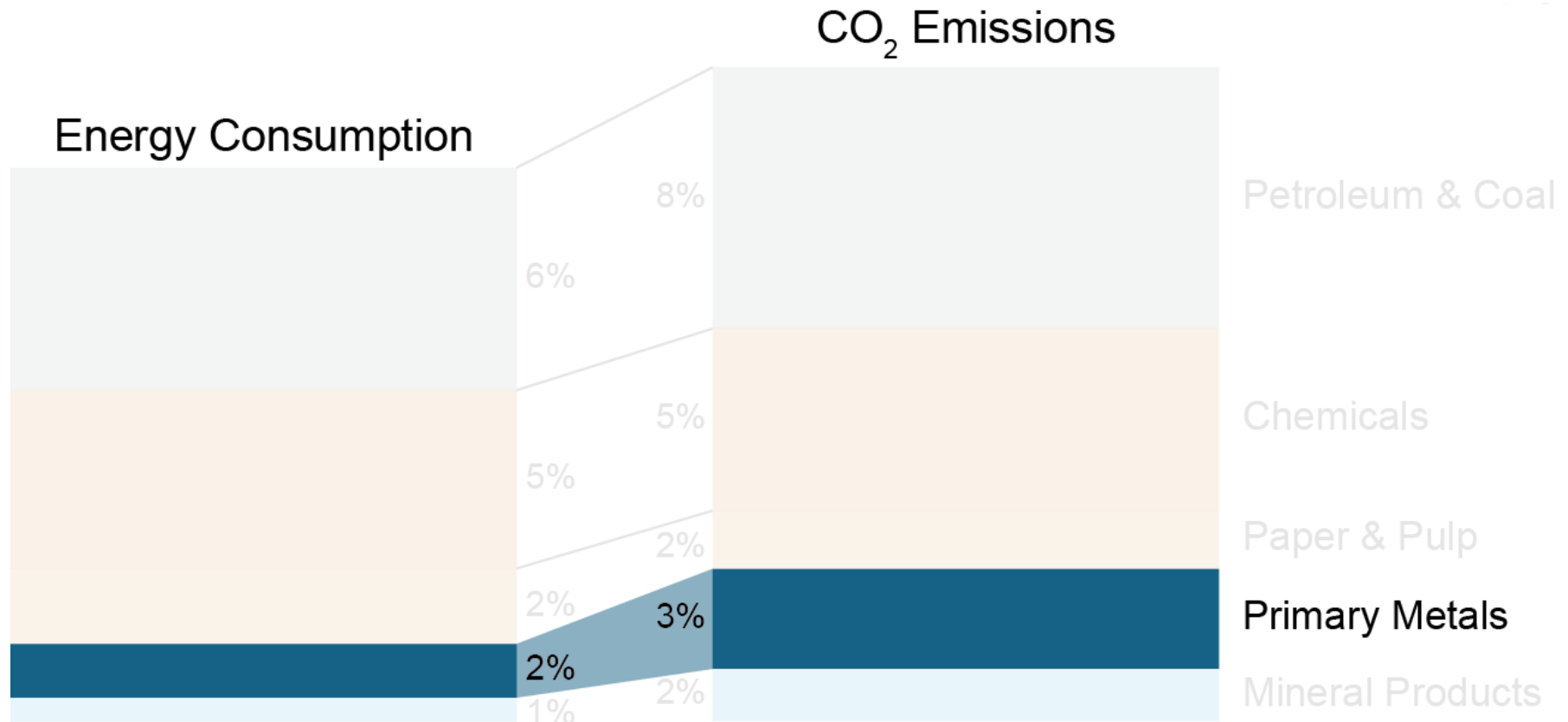
Microorganisms for Metals:

Opportunities for Biology in the Mining Industry

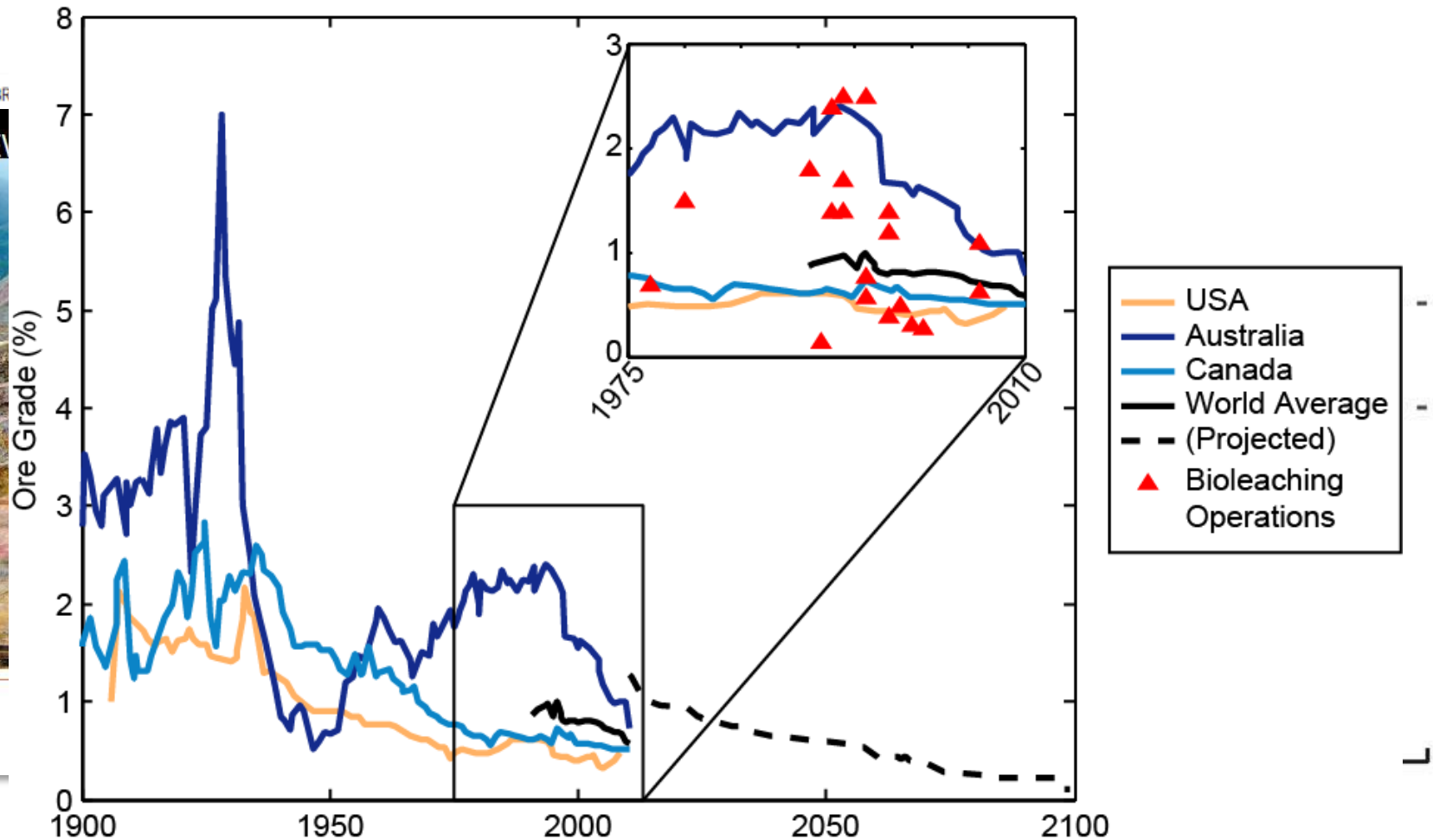
Brad Zamft, PhD, ARPA-E Fellow



Manufacturing Composes a Disproportionate Component of Emissions



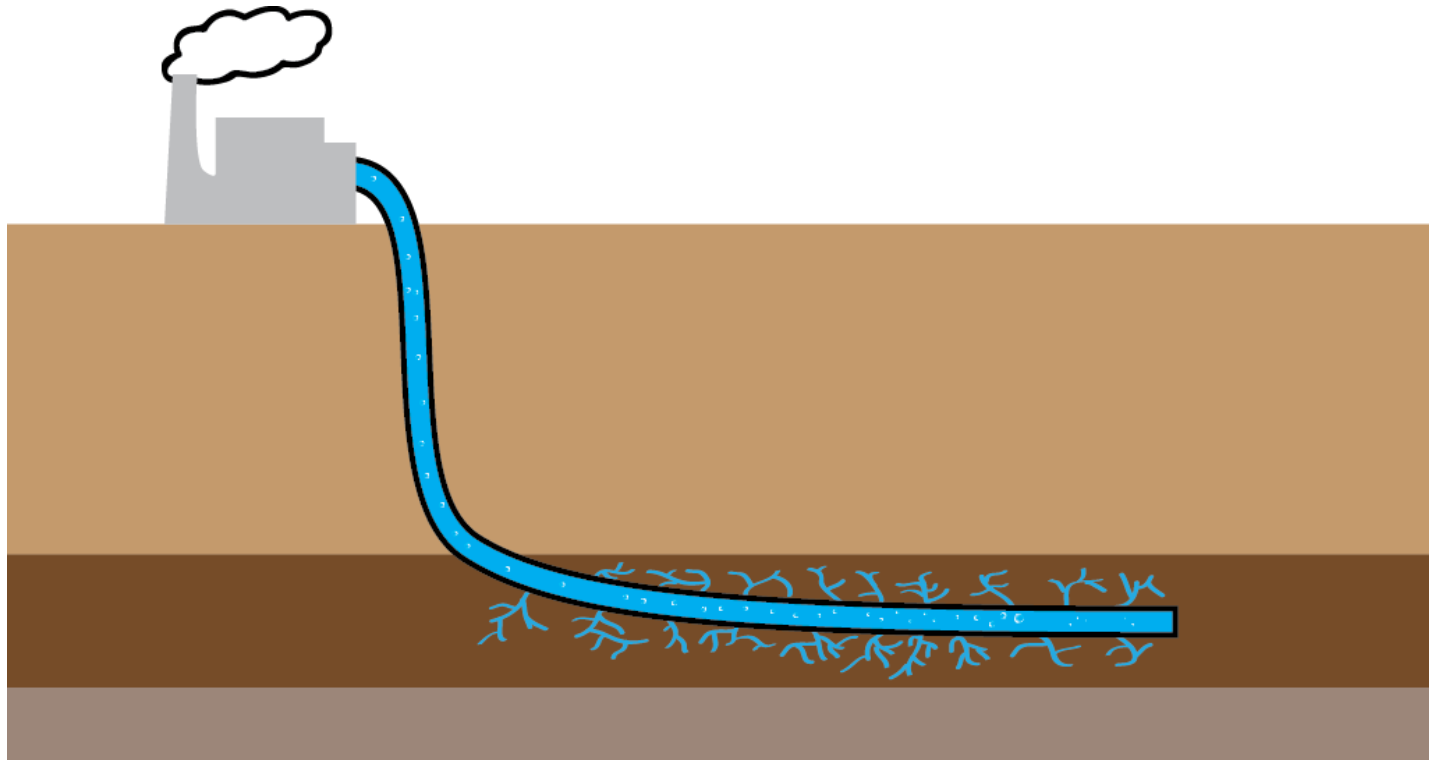
Copper: the Next Energy Critical Material?



Current Mining Practices are Environmentally Intensive



Bringing Horizontal Drilling to Mining



Open Pits to Directional Wells



VS.



Downhole Leaching is Commercially Viable

- ▶ *In situ* leaching of uranium ore
 - 90% of the uranium mined in the US
 - 40% of the world's production in 2010
 - Sand beds – easy to leach
- ▶ Not currently feasible for other metals
- ▶ **Environmental concerns:** 1000 ft depth vs. miles
- ▶ *In situ* bioleaching considerations
 - Gas delivery
 - Biology of leaching

Metallofuels: Harnessing Mineral Energy

Per kg Butanol Produced

Ore	Cu (kg)	Fe (kg)	H ₂ O (L)	O ₂ (kg) (consumed)	CO ₂ (kg) (consumed)
CuFeS ₂	0.6-0.8	0.5-0.7	1-2	4-5	2
FeS ₂		1	1	5-13	2
10 H ₂ O					

Oxidation of pyrite to sulphate

Ore	Metal	2011 Global Production (M MT) ¹	ΔG (kJ/mol) ²	% Primary Energy	Value (WTI)
CuFeS ₂	Cu	16	-2200	0.1	\$9 B
	Fe	1090		9	\$800 B
FeS ₂	Fe		-1200	5	\$400 B



CHANGING WHAT'S POSSIBLE

The Far Future of the Energy & Water Nexus

Dr. Amul D. Tevar, ARPA-E Fellow

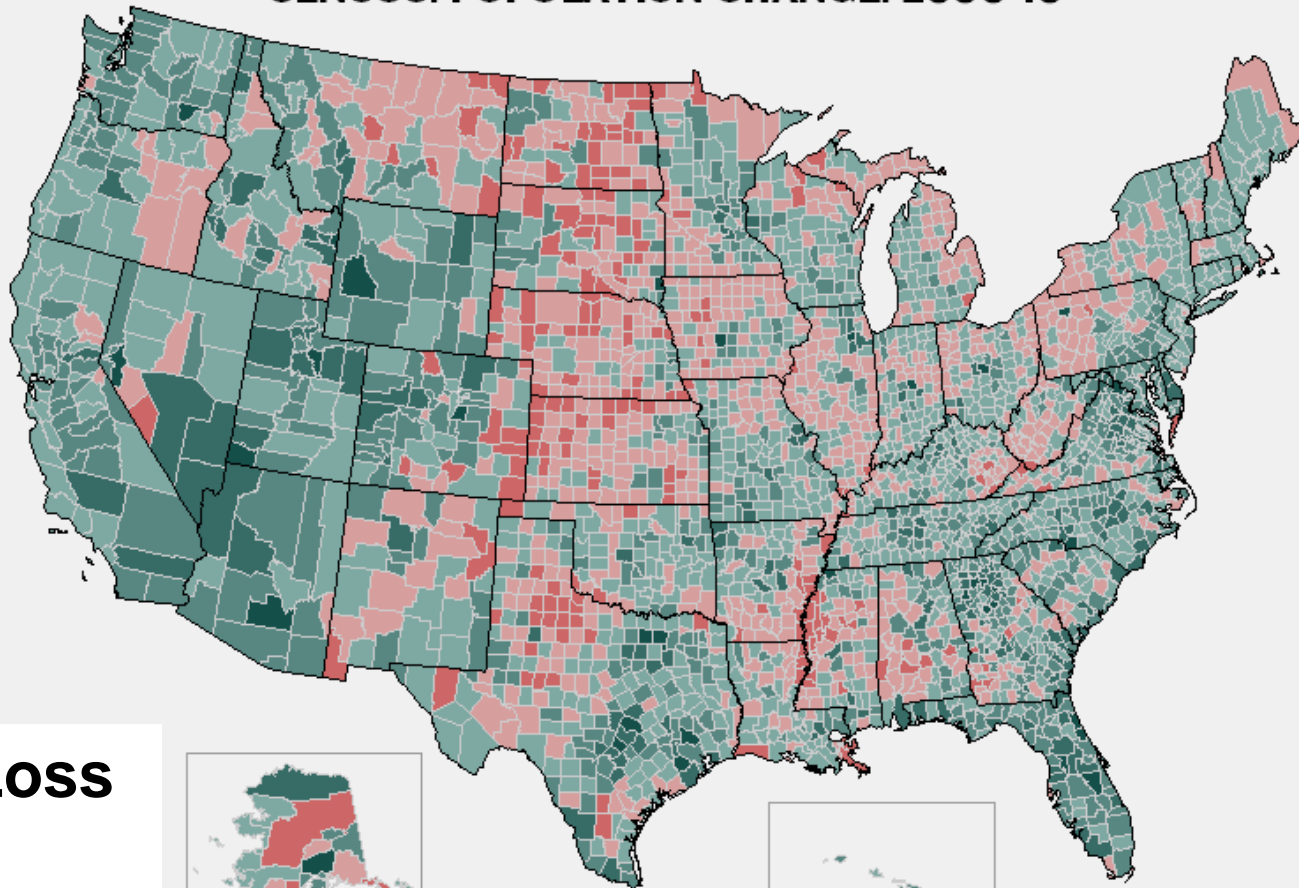
February 24, 2014

Legacy Inefficiencies in Infrastructure



Shift from Rural to City-States

CENSUS: POPULATION CHANGE: 2000-10

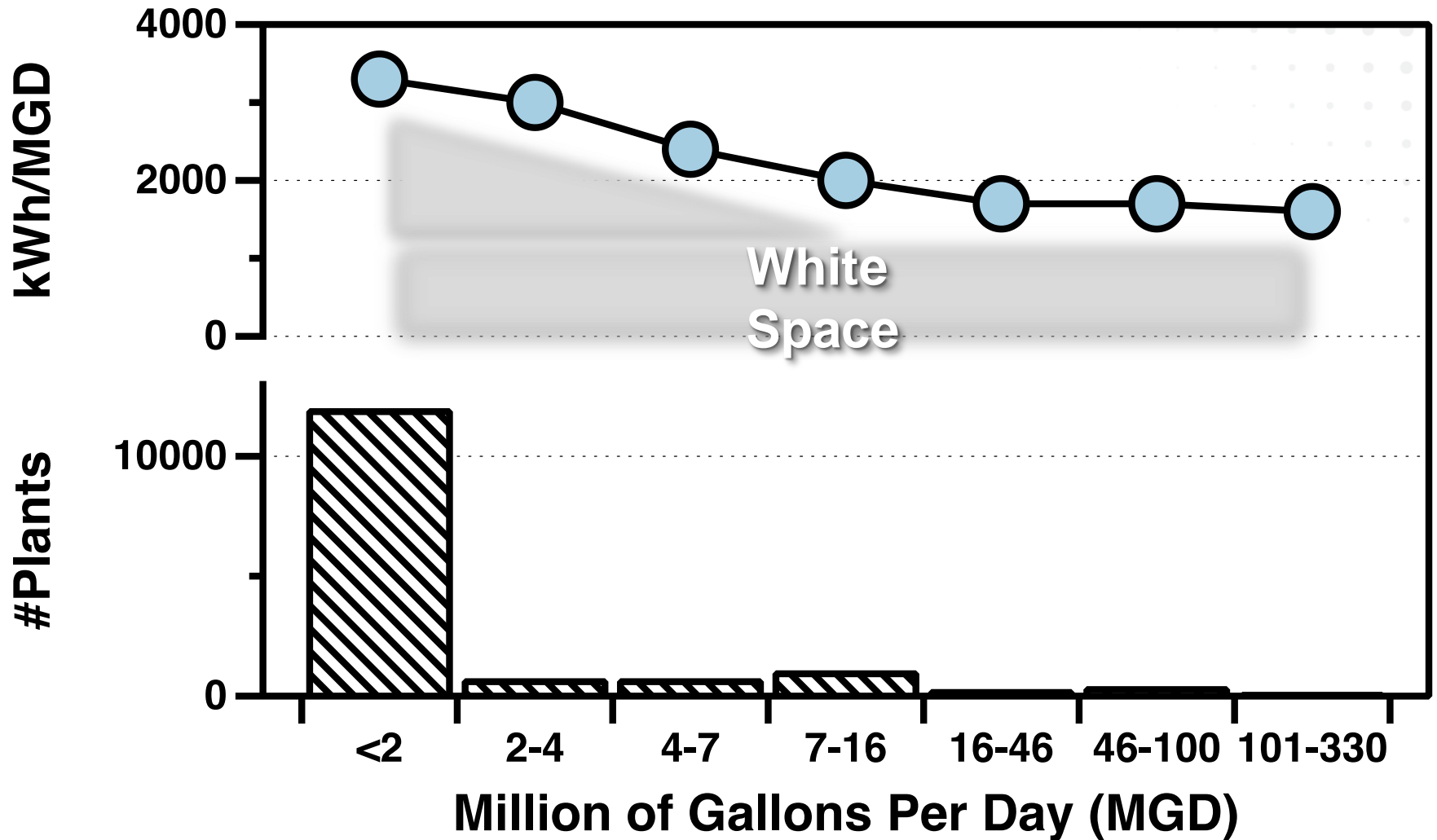


 = Popl. Loss

 = Popl. Gain

Source: U.S. Census Bureau/IRE

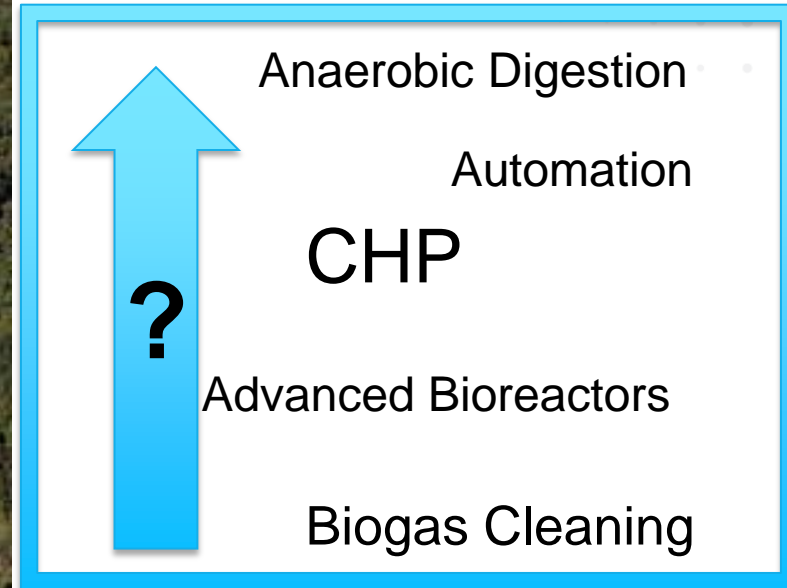
~1 Quad for Wastewater



Scoop on Poop: Energy Positive Treatment

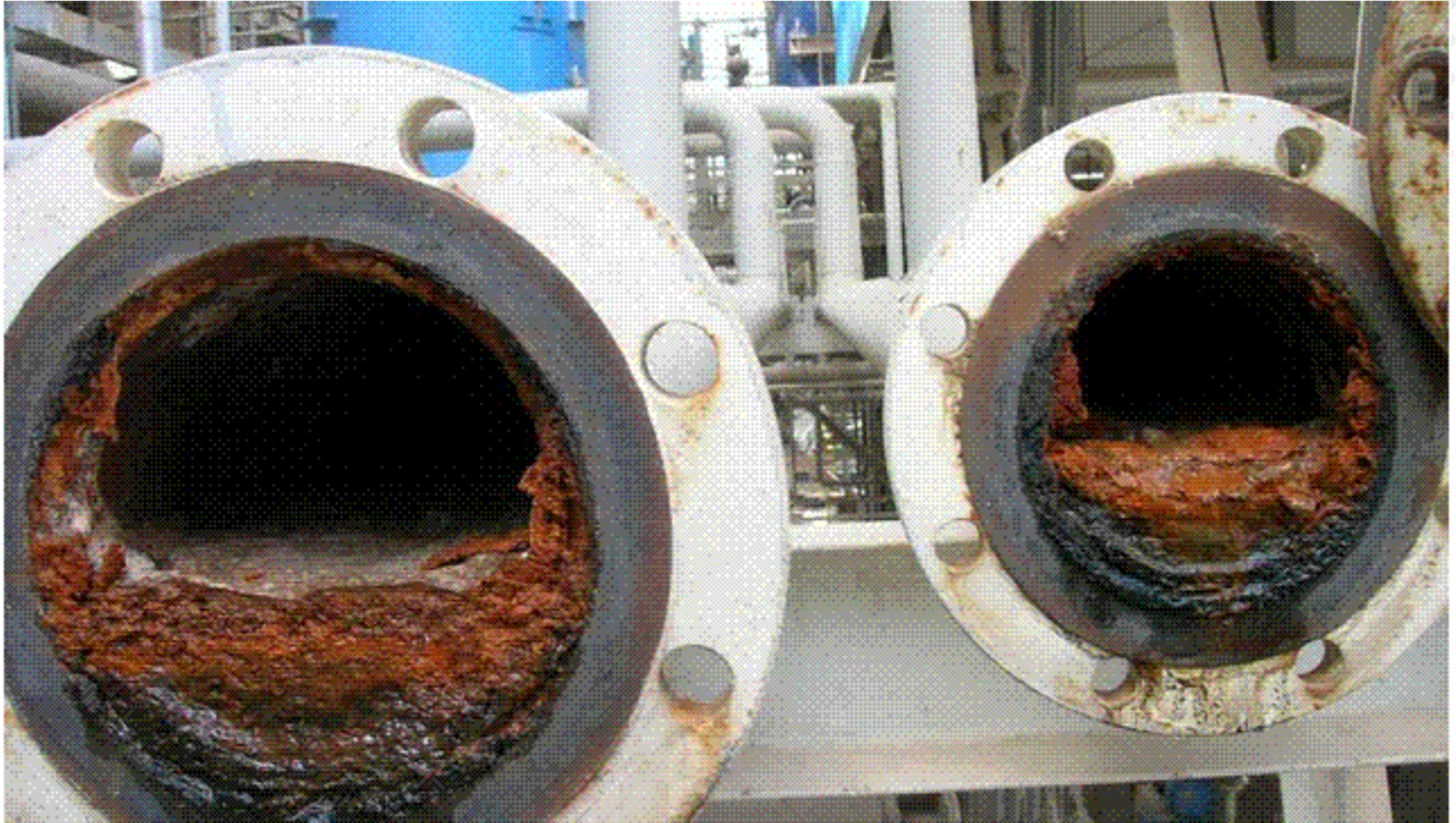


**Future: +100 kWh/MGD
Small Scale**

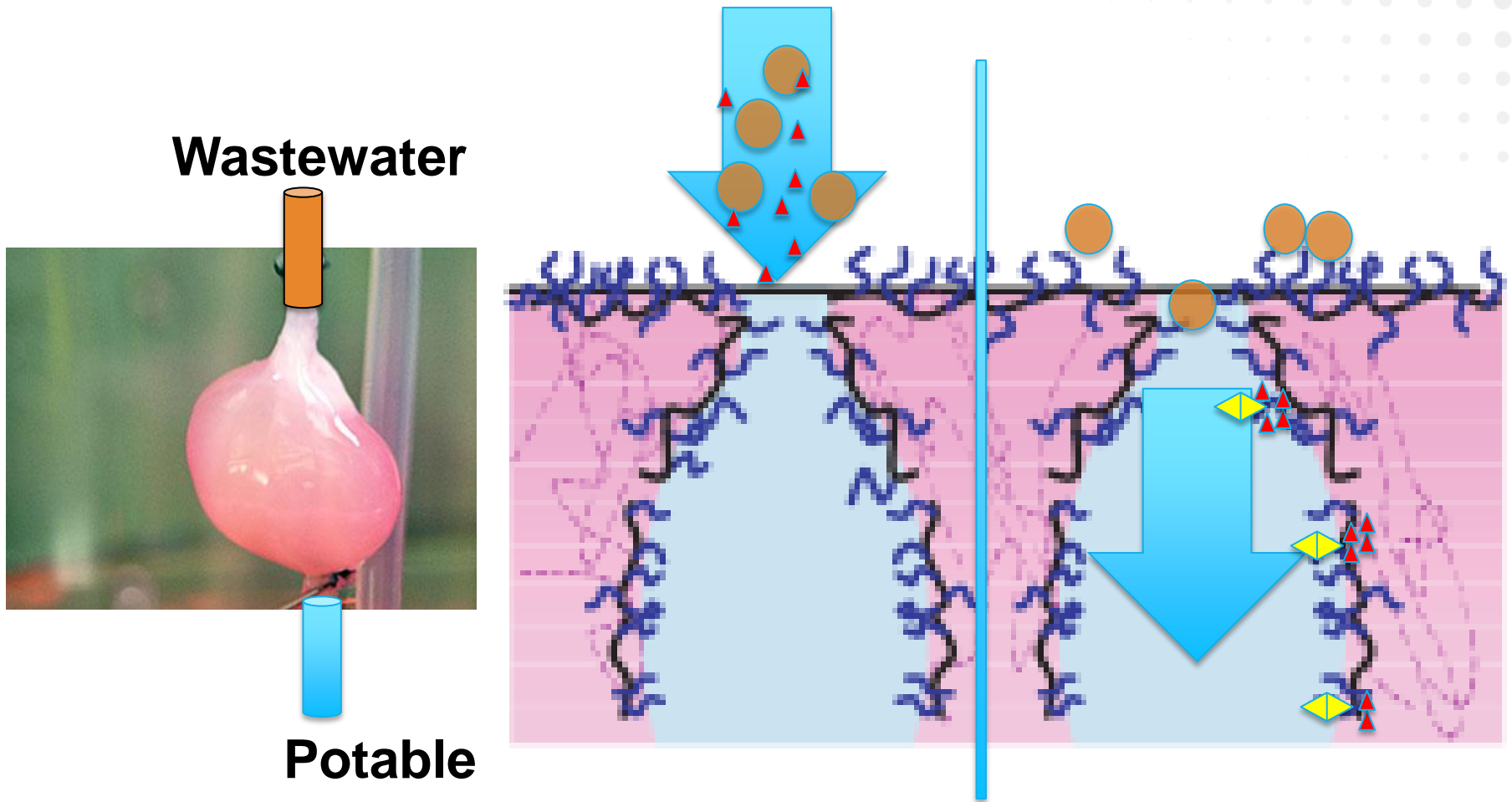


**Current: -1600 kWh/MGD
Large Scale**

Biofouling Limits Membranes



Biomimetic Membranes: Stealing a Kidney



We All Share the Sources



Email: amul.tevar@hq.doe.gov



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ENERGY

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